ASSP For Power Supply Applications

Switching Regulator Controller

MB3776A

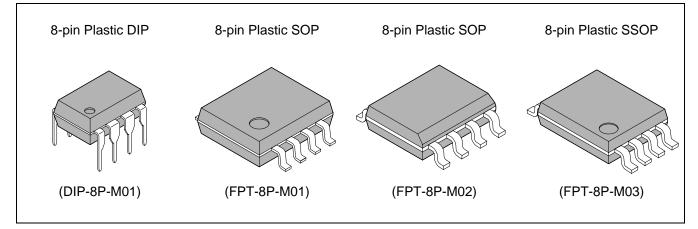
DESCRIPTION

MB3776A is a PWM system switching regulator controller. Because of its low operating supply voltage and powerdown, the MB3776A is ideal for use in DC/DC converters for battery-powered portable equipment.

FEATURES

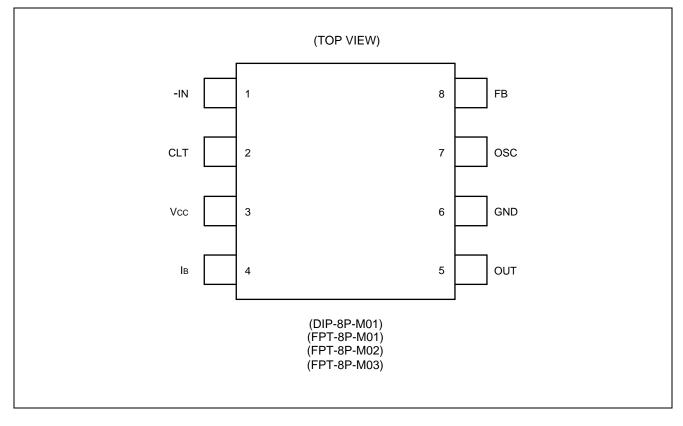
- Wide supply voltage range: (2 V to 15 V)
- Wide oscillation frequency range, high-frequency oscillation: (10 kHz to 500 kHz)
- · Push-pull output. Drive current set with external resistor
- Bulit-in idle period circuit
- · Internally set error amplifier gain, few external components
- Bulit-in power-down function

PACKAGES

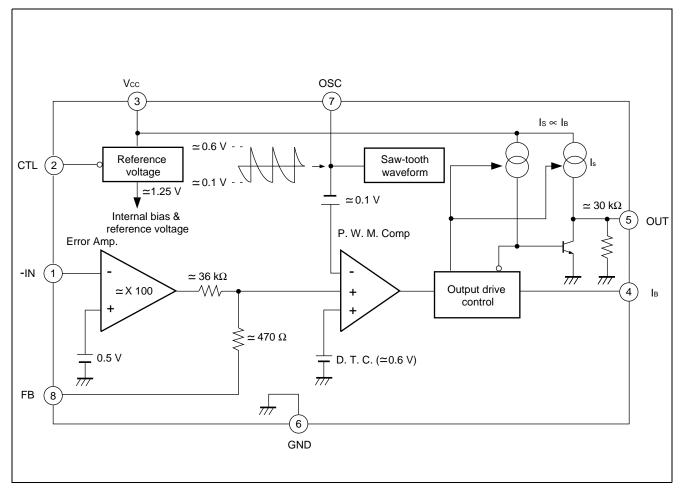




■ PIN ASSIGNMENT



BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

					``	a = +25°C
Parameter	Symbol	Condition		Ra	ting	Unit
					Max	
Power supply voltage	Vcc			—	16	V
Error amp. input voltage	Vı			-0.3	+10	V
Output source current	ISOURCE			—	-50	mA
Output sink current	Isink	—		_	50	mA
		Ta ≤ +25°C (DIP)		_	550	mW
Dower dissipation	Pp	$T_{0} < 125^{\circ}C(SOD)$	EIAJ	_	*570	mW
Power dissipation	PD	Ta ≤ +25°C (SOP)	JEDEC	_	*430	mW
		Ta < +25°C (SSOP)		_	*580	mW
Operating temperature	Тор	_		-30	+75	°C
Storage temperature	Tstg	_		-55	+125	°C

*: The packages are mounted on the epoxy board (10 cm \times 10 cm \times 1.5 mm)

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol		Value		Unit
Faiameter	Symbol	Min	Тур	Max	Unit
Power supply voltage	Vcc	2.0		15	V
Error amp. input voltage	Vı	-0.2		1.0	V
Output source current	ISOURCE	-40			mA
Output sink current	Isink			40	mA
Phase compensation capacitor	СР		0.1		μF
Timing capacitor	Ст	100	1000	10000	pF
Timing resistor	R⊤	1.0	3.0	5.0	kΩ
Oscillator frequency	fosc	10	200	500	kHz
Operating temperature	Тор	-30	25	75	°C

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

ELECTRICAL CHARACTERISTICS

1. Reference Section and Error Amp. Section

 $(Ta = +25^{\circ}C, Vcc = 3 V)$

Parameter	Symbol	Condition		Unit		
Parameter Symbol		Condition	Min	Тур	Max	Unit
Input threshold voltage	Vт	V _{FB} = 450 mV	487	507	527	mV
V⊤ input stability	V _{TdV1}	Vcc = 2.0 V to 6.0 V	-5		5	mV
	VTdV2	Vcc = 6.0 V to 15 V	-5		5	mV
V⊤ temp. stability	Vtdt	Ta = -30 °C to +75 °C	-3		3	%
Input bias current	Ів	V _{IN} = 0 V to 0.6 V	-1.0	-0.2	1.0	μΑ
Voltage gain	Av	—	70	100	145	V/V
Frequency band width	BW	$A_V = 0 dB$	—	6		MHz

2. Saw-tooth Waveform Oscillator Section

 $(Ta = +25^{\circ}C, Vcc = 3 V)$

Parameter	Symbol	Condition		Unit		
Farameter	Symbol	Condition	Min	Тур	Max	Unit
Oscillator frequency	fosc	R _T = 3.0 kΩ C _T = 1000 pF	160	200	240	kHz
Frequency input stability	fdv	Vcc = 2.0 V to 15 V		±2		%
Frequency temp. stability	fdт	$Ta = -30^{\circ}C$ to $+75^{\circ}C$	_	±10	—	%

3. Under Lockout Protection

(Ta = +25°C, Vcc = 3 V)

Parameter	Symbol	Condition		Unit		
rarameter	Symbol	Condition	Min	Тур	Max	Unit
Threshold voltage	Vth	_		1.4		V

4. Dead-time Control Section

(Ta = +25°C, Vcc = 3 V)

Paramotor	Parameter Symbol	Condition	Value			Unit
Falameter		Condition	Min	Тур	Max	Onit
Max duty cycle	t duty	C _T = 1000 pF R _T = 3.0 kΩ V _{FB} = 0.9 V	60	70	85	%

5. Output Section

(Ta = +25°C, Vcc = 3 V)

Parameter Svr		Symbol Condition		Value			
Faiameter	Symbol	Condition	Min	Тур	Max	Unit	
Output source current	ISOURCE	R _B = 820 Ω, Vo = 1 V	-40	-30	-20	mA	
Output sink current	ISINK	R _B = 820 Ω, Vo = 0.3 V	30	60		mA	
High-level output voltage	Vон	$R_B = 820 \Omega$, $V_0 = 7 V$ $I_0 = -15 mA$	5.5	6.0		V	
Output voltage	Vol	$V_{CTL} = V_{CC}$, Io = 3 μ A	—	0.1	0.2	V	

6. Control Section

 $(Ta = +25^{\circ}C, Vcc = 3 V)$

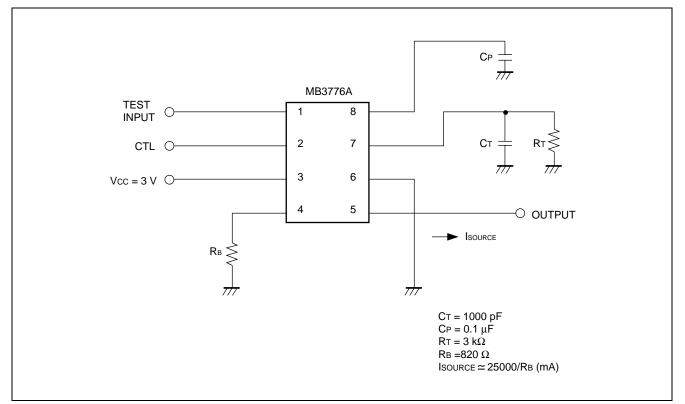
Parameter	Symbol Condition				Unit	
Faiameter	Symbol			Тур	Max	Unit
Input off condition	OFF	—	-300	_	_	μΑ
Input on condition	ION	_	_		-700	μΑ
Control terminal current	Іст∟	$V_{CC} = 7 \text{ V}, \text{ V}_{CTL} = 0 \text{ V}$	-1.3	-1	—	mA

7. All Device

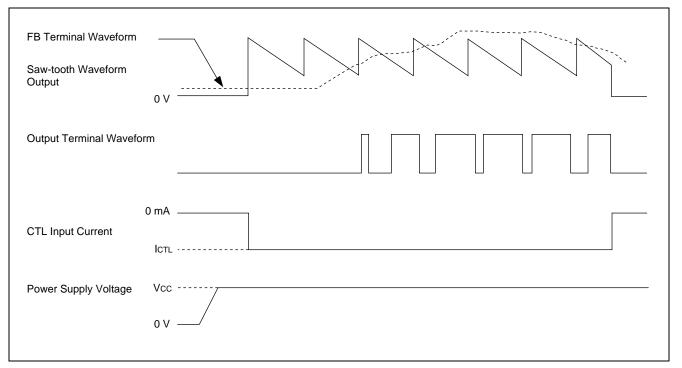
(Ta = +25°C, Vcc = 3 V)

Parameter	Symbol	Condition		Unit		
Farameter	Symbol	Condition	Min	Тур	Max	Unit
Stand by current	lccs	V _{CTL} = V _{CC} or CTL terminal open	_	_	0.5	μΑ
Average supply current	lcc	Ictl = -700 μA R _B = 820 Ω	_	4.5	8	mA

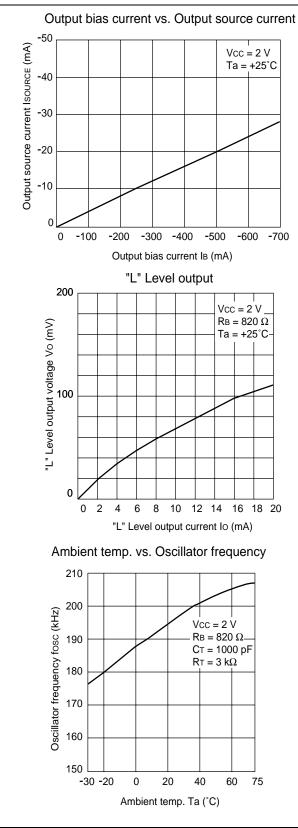
■ MEASURMENT CIRCUIT

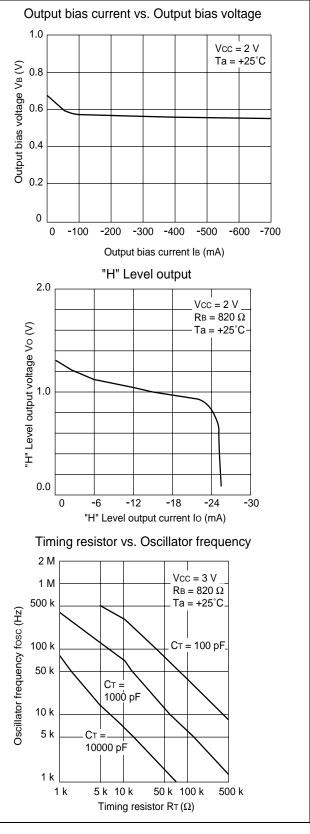


DIAGRAM

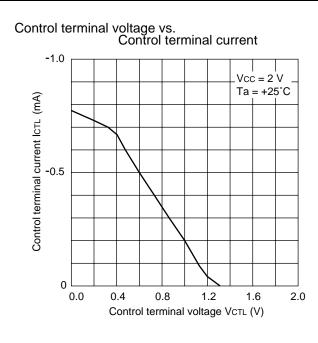


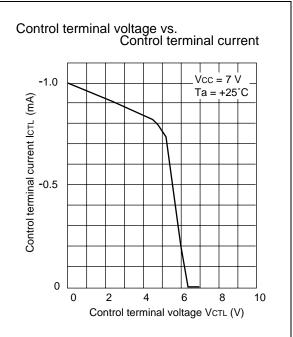
TYPICAL CHARACTERISTIC



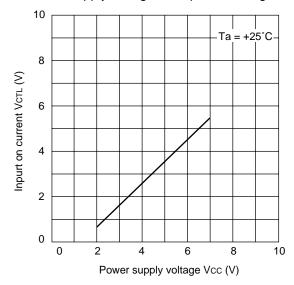


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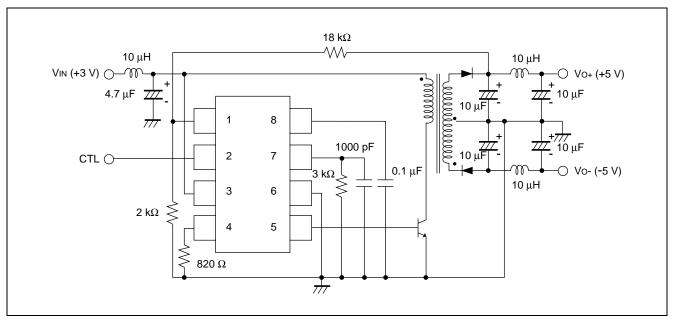




Power supply voltage vs. Input on voltage

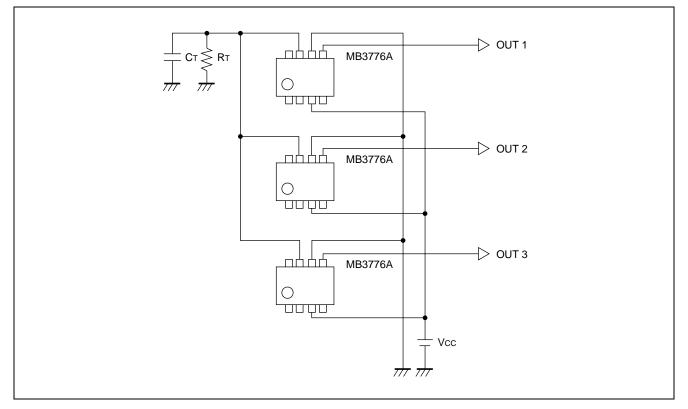


■ APPLICATION EXAMPLE



Synchronization

To synchronize MB3776A controllers, the OSC terminal of each IC is shared and the same specified capacitor and resistor used on a signal IC application is connected for self-excitation oscillation. The CTL terminal controls power on/off of each IC.



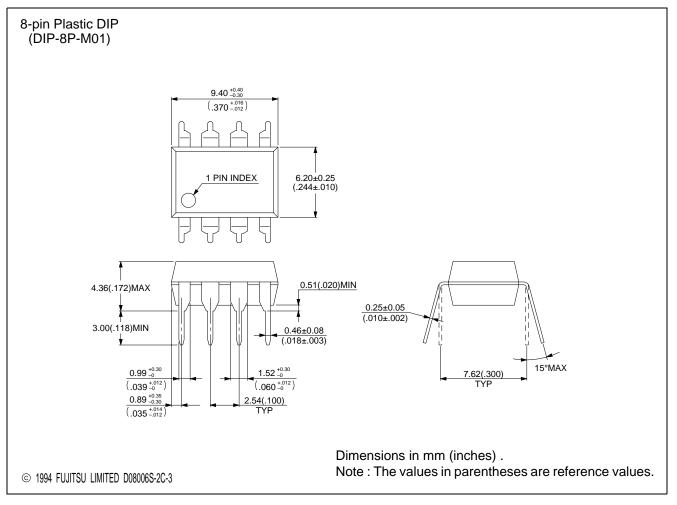
NOTES ON USE

- Take account of common impedance when designing the earth line on a printed wiring board.
- Take measures against static electricity.
 - For semiconductors, use antistatic or conductive containers.
 - When storing or carrying a printed circuit board after chip mounting, put it in a conductive bag or container.
 - The work table, tools and measuring instruments must be grounded.
 - The worker must put on a grounding device containing 250 k Ω to 1 $M\Omega$ resistors in series.
- Do not apply a negative voltage
 - Applying a negative voltage of –0.3 V or less to an LSI may generate a parasitic transistor, resulting in malfunction.

Part number	Package	Remarks
MB3776A-P	8-pin Plastic DIP (DIP-8P-M01)	
MB3776APF	8-pin Plastic SOP (FPT-8P-M01)	
MB3776APNF	8-pin Plastic SOP (FPT-8P-M02)	
MB3776APFV	8-pin Plastic SSOP (FPT-8P-M03)	

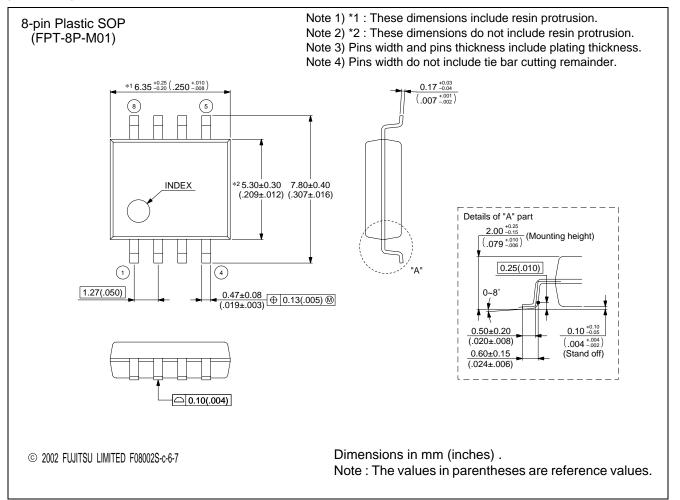
ORDERING INFORMATION

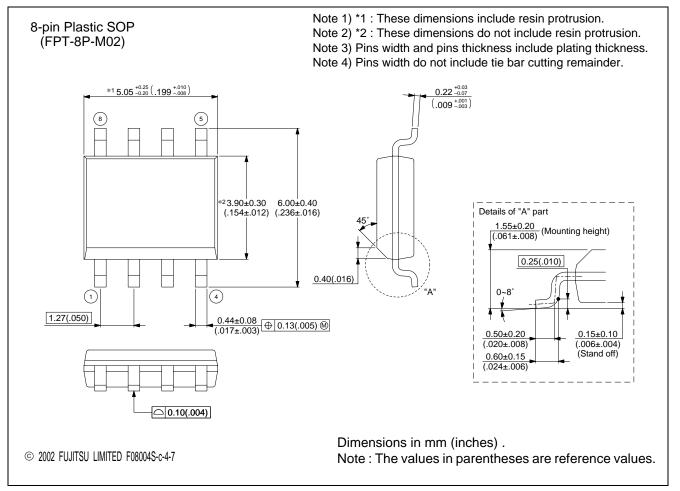
■ PACKAGE DIMENSIONS

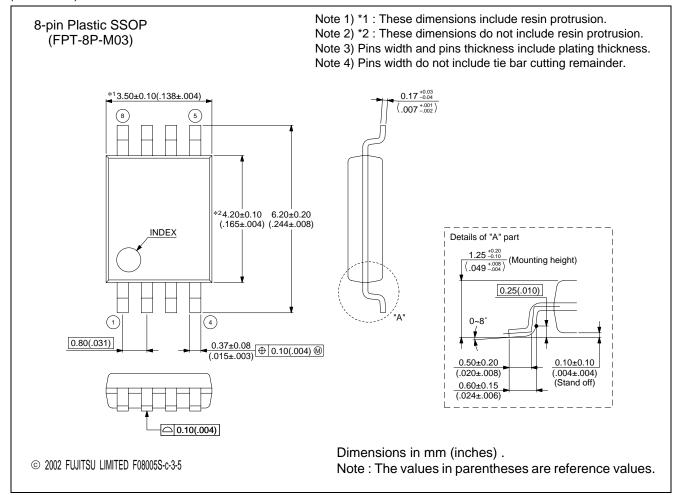




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